Quantum heat engine power can be increased by noise-induced coherence

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Contributed by Marlan O. Scully, July 1, 2011 (sent for review June 20, 2011)

Laser and photocell quantum heat engines (QHEs) are powered by thermal light and governed by the laws of quantum thermodynamics. To appreciate the deep connection between quantum mechanics and thermodynamics we need only recall that in 1901 Planck introduced the quantum of action to calculate the entropy of thermal light, and in 1905 Einstein’s studies of the entropy of thermal light led him to introduce the photon. Then in 1917, he discovered stimulated emission by using detailed balance arguments.

Half a century later, Scovil and Schulz-DuBois applied detailed balance ideas to show that maser photons were produced with Carnot quantum efficiency (see Fig. 1A). Furthermore, Shockley and Quisser invoked detailed balance to obtain the efficiency of a photocell illuminated by “hot” thermal light (see Fig. 2A). To understand this detailed balance limit, we note that in the QHE, the incident light excites electrons, which can then deliver useful work to a load. However, the efficiency is limited by radiative recombination in which the excited electrons are returned to the ground state.

Here we show that noise-induced coherence enables us to break detailed balance and yield lasing without inversion. However, the efficiency is limited by radiative recombination in which the excited electrons are returned to the ground state. But it has been proven that radiatively induced quantum coherence can break detailed balance and yield lasing without inversion. Here we show that noise-induced coherence enables us to break detailed balance and get more power out of a laser or photocell QHE. Surprisingly, this coherence can be induced by the same noisy (thermal) emission and absorption processes that drive the QHE (see Appendix). Furthermore, this noise-induced coherence can be robust against environmental decoherence.

Quantum mechanics began with the thermodynamic studies of Planck (1) and Einstein (2). In later work Einstein introduced the concept of stimulated emission via the detailed balance arguments (3). After the advent of the maser, Scovil and Schulz-DuBois (4) showed the quantum efficiency for the maser is described by a Carnot relation, and Shockley and Quisser (5) used detailed balance limit to obtain a similar relation for a photocell. However, in the later part of the twentieth century it was shown that detailed balance could be superseded by using quantum coherence; this is manifested in lasing without inversion (6–8).

Recent studies of a photocell QHE (9) show that it is possible to use microwave induced coherence to break detailed balance and enhance quantum efficiency (i.e., open circuit voltage). But what about enhancing the cell power? It takes energy to generate the microwaves—can we avoid this? A similar question can be asked concerning the laser QHE: Can we use quantum coherence to increase the net emitted laser power? More to the point, can we increase the power output of, for example, a photocell by using noise-induced coherence (10) such as that produced by Fano interference, to break detailed balance? The perhaps surprising (11) answer is yes.*

To answer this question, let us consider the case in which the lowest level is replaced by the pair of levels as in Fig. 1C. Now the plot thickens. In addition to producing a population inversion, the hot and cold photons can induce coherence between levels $b_1$ and $b_2$; where the amount of coherence is determined by the off diagonal matrix elements (12, 13) $p_{b_1b_2} = p_{12}$ given in Eq. 3. We find that this coherence can markedly enhance the power [see also Fleischhauer et al. (14, 15) and Kozlov et al. (16)].

The coherence induced by the hot and cold thermal radiation can be obtained from the density matrix equations of motion (see Appendix). To understand the physical origin of the noise-induced coherence we consider the probability $\rho_{11}$ of being in the state $b_1$, which obeys the following equation of motion with physical interpretation depicted on the next line:

$$\rho_{11} = γ_{1b}(1 + \bar{a}_b)a_{1b} - \bar{a}_bρ_{b1} + γ_{b1}(1 + \bar{a}_b)a_{b1} - \bar{a}_bρ_{1b} - \bar{a}_b\rho_{b1}$$

$$= β + \beta + \beta.$$  

Here $γ_{kb}(γ_{bk}), k = 1, 2$, is the spontaneous emission rate of the $β → b_k$ ($a → b_k$) transition, $γ_{12}(γ_{21})$ are cross-coupling coefficients that describe the effect of interference (17), $\bar{a}_b$ and $\bar{a}_c$ are average number of hot and cold thermal photons (17) given by the Planck factors $\bar{a}_b = (\exp(E_a - E_b)/kT_b - 1)^{-1}$, $\bar{a}_c = (\exp(E_b - E_c)/kT_c - 1)^{-1}$.

The power generated by the laser is

$$P_l = \frac{γ_{21}}{γ_{12}}(a_{b1} - a_{1b})\bar{a}_b.$$  

*At least it seems to surprise Kirk (11), who says incorrectly: “As Harris shows in his 1989 work on lasing without inversion, Fano interference does not break detailed balance.”

We disagree, as does Harris, and we thank him for allowing us to so report. Quantum noise-induced coherence can indeed increase power output, as clearly shown in Fig. 3.

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Author contributions: M.O.S. conceived the project, carried out the first calculations, and wrote the first draft of the paper; M.O.S., K.E.D., and A.S. designed the research; M.O.S. and A.S. designed new analytical tools; A.S. showed that the coherence can be robust; and M.O.S., K.R.C., K.E.D., and M.B.K. wrote the paper.

The authors declare no conflict of interest.

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This article contains supporting information online at www.pnas.org/lookup/suppl/doi:10.1073/pnas.1110234108/-/DCSupplemental.

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Fig. 1. (A) Schematic of a laser pumped by hot photons at temperature $T_h$ (energy source, blue) and by cold photons at temperature $T_c$ (entropy sink, red). The laser emits photons (green) such that at threshold the laser photon energy and pump photon energy is related by Carnot efficiency (4). (B) Schematic of atoms inside the cavity. Lower level $b$ is coupled to the excited states $a$ and $b$. The laser power is governed by the average number of hot and cold thermal photons, $\bar{a}_b$ and $\bar{a}_c$. (C) Same as $B$ but lower $b$ level is replaced by two states $b_1$ and $b_2$, which can double the power when there is coherence between the levels.
where $n_i$ is the average number of laser photons, $g$ is atom-field coupling constant, and $\gamma_i$ is the spontaneous decay rate at the lasing transition $a \to b$.

Thus, as discussed in Appendix and in SI Text, we solve the density matrix equations for populations $p_{\alpha\alpha}$ and $p_{\beta\beta}$ as well as quantum coherence $\rho_{\alpha\beta}$ in steady state. For $\gamma_B = \gamma_2b = \gamma_e$, $E_{jC} = \gamma_e$, the maximum coherence and laser power (18) are given by

$$\rho_{ij} = \frac{P_i}{4\gamma_i n_i \hbar \omega}, \quad P_i = A(\tilde{n}_i - n_i)\hbar \omega_i,$$  \hspace{1cm} [3]

where rate $A$ is a function of decay rates $\gamma_e$ and $\gamma_B$ and the Planck average photon numbers $\tilde{n}_i$, $n_i$ (see Appendix and SI Text). For the appropriate choice of parameters $A = \gamma_B$ for the system with no coherence and $A = \gamma_B$ with coherence—i.e., the power can be doubled (18), as in Fig. 1. Furthermore, Figs. 1 and 3 show that laser power can be significantly enhanced in the presence of coherence in general. Physically this is because the coherence can lead to faster removal of atoms from the ground state $b_{1,2}$ to the upper laser level $a$ increasing useful work. That is, quantum coherence and interference enhances absorption of solar photons; because the $\gamma_2$ term results in redistribution of the population between $b_1$ and $b_2$ states such that the state with stronger coupling to the upper level $a$ becomes more populated. This increases the number of absorbed photons and the current through the cell. Such interference can enhance photon absorption as in the present model or suppress it, which is the case for lasing without inversion.

Next we consider the photocell QHE of Fig. 2 and study the influence of quantum interference and coherence on PV operation (i.e., power generated). Here we will consider a narrow band of frequencies as in the case of a multiplex array of photovoltaics. That is, to optimally utilize a broad solar spectrum one can divide the incident solar flux into narrow frequency intervals, each of which is directed to a quantum dot photocell with its energy space matched to the incident light. Monochromatic solar radiation excites electrons from the valence to conduction states in the quantum dots. The “built-in” field in the depletion layer separates electrons and holes; however, they can radiatively recombine before being separated. In the complete analysis (see SI Text) we consider the general coupling associated with emission and absorption of solar photons and thermal phonons. This requires a little more elaborate density matrix treatment but the physics is essentially the same as the preceding laser problem. Furthermore, we here focus on the power generated, not the open circuit voltage, as is the case in ref. 9. However, the issue of breaking detailed balance in a photocell via quantum coherence remains the essence of the problem.

In the photocell model (19, 20) of Fig. 2 B and C the cell current $j$ and voltage $V$ between levels $\alpha$ and $\beta$ are given by (see Appendix)

$$j = e \Gamma p_{\alpha\alpha} \quad \text{and} \quad eV = E_{\alpha} - E_{\beta} + kT_e \ln \left( \frac{p_{\alpha\alpha}}{p_{\beta\beta}} \right).$$  \hspace{1cm} [4]

where $\Gamma$ is the decay of level $\alpha$ and $p_{ij}(i = \alpha, \beta)$ are the occupation probabilities of states in the conduction and lower energy valence reservoirs having energies $E_{\alpha}$ and $E_{\beta}$. If levels $b_1$ and $b_2$ are degenerate and $\gamma_B = \gamma_2b = \gamma_e$ the quantum coherence and power $\propto jV$ are found to be

\footnote{In the strong pump limit, $\tilde{n}_i \gg 1, n_i \ll 1, \gamma_i \ll \gamma_e$, the laser power is given by the simple expression shown in Fig. 1 B and C where $\gamma_i$ is the radiative decay rate from $a \to b$ and hot and cold photon Planck factors $\tilde{n}_i, n_i$ are discussed in the text.}

\footnote{For instance if $\beta_i > 1, n_i \ll 1, \gamma_i \ll \gamma_e$.}

\footnote{In this case the maximum current $j$ is comparable to the current generated by incoherent double $2 \gamma_i \hbar \omega_i$ for a single lower level as per Eq. 2B. As per Fig. 3A simulation we take $T_e = 0.5$ eV, $T_0 = 0.0259$ eV, $E_e = E_0 = 1.43$ eV, $E_a = 0.05$ eV, $\gamma_0 = 0.027$, $\gamma_2 = 50\gamma_0$, $\gamma_e = 5\gamma_2$. In addition for a photocell QHE $E_a = E_0 = 0.05$ eV and $\gamma_0 = 50\gamma_2$, $\gamma_2 = 50\gamma_0$, $\gamma_e = 5\gamma_2$.}

\footnote{As an illustration we consider a model in which levels $b_1$ and $b_2$ are degenerate and take $T_e = 0.5$ eV, $T_0 = 0.0259$ eV, $E_e = E_0 = E_a = 0.002$ eV, $E_a = E_0 = 1.4296$ eV, $\gamma_0 = 0.027$, $\gamma_2 = 50\gamma_0$, $\gamma_e = 10^3\gamma_2$, and $\gamma_{\alpha\alpha} = 50\gamma_2$.}

which is similar to Eq. 3 for the laser QHE in which the laser photon flux $P_i/\hbar \omega_\alpha$ is now replaced by the photocell current. Factor $B$ is similar to $A$ and for the appropriate choice of parameters $B = \gamma_e/2$ for the system with singlet shown in Fig. 2B, $\beta = 2\gamma_2/\gamma_0$ for the doublet model (Fig. 2C), and no coherence and $B = \gamma_e$ with full coherence—i.e., the photocell QHE power can be doubled by quantum coherence just as in the case of the laser.

Fig. 3A shows the photocell current $j$ (photon flux $P_i/\hbar \omega_\alpha$) as a function of voltage (energy) of the electrons (laser photons). We find that the induced coherence substantially increases the cell current (photon flux) and therefore the power of the QHE. As in the laser QHE, quantum coherence in the photocell QHE results in the faster removal of electrons from the recombination region, so that we can reduce the $a \to b_{1,2}$ transition and enhance the photocurrent $\alpha \to \beta$. This reduces recombination losses and increases the power delivered to the load. For example, in the limit of a weak pump, $\tilde{n}_i \ll 1$, appropriate for a photodetector, the signal power is doubled by quantum coherence (see Fig. 2B and C).

It is important to note that effects of environmentally induced decoherence $\tau_\alpha$ on photocell power can be made small by proper cell design. For the typical case in which the phonon occupation number $\tilde{n}_i$ is large, Eq. 8 shows that the stimulated photon absorption $(\gamma_i + \gamma_2 \tilde{n}_i)$ term dominates other possible decoherence channels ($\gamma_2$ effects) even when the environmental effect is substantial $(\tau_\alpha \gg \gamma_1)$. As a result, one can have a photocell with PV characteristics shown in Fig. 3A such that the noised induced quantum coherence is robust against environmental decoherence.

To summarize: There exists a close analogy between the laser QHE pumped by hot photons and cooled by a lower temperature entropy sink and a photocell QHE that is driven by hot photons while the ambient heat reservoir serves as the lower temperature entropy sink (21). Furthermore, we have shown that quantum
interference can enhance laser and PV thermodynamic power beyond the limit of a system, which does not possess quantum coherence. Moreover, coherence generated by noise-induced quantum interference is essentially different from the quantum coherence produced by an external microwave field (9), which costs energy. In the present paper, quantum coherence is generated by the photocurrent due to quantum interference. No additional energy source is necessary to create such induced coherence. Nevertheless, as we have shown, the induced coherence can, in principle, enhance the efficiency of photovoltaic devices such as solar cells and/or photodetectors. We note that in the case of solar cells, the power generated is always less than the incident power times the Carnot factor—i.e., $P < P_{\text{solar}}$ $(1 - \frac{T_0}{T_1})$. In the case of photodetector operating at low temperature the phase coherence time $T_2$ can be relatively long, and applications of the present work to photodetection near at hand. Practical application to solar cell systems is possible but requires further research. However it is clear that the ultimate “in principle” limit of such devices is an important question of fundamental interest.

**Appendix**

Here we give (see SI Text for more detail) the density matrix equations for a laser QHE model of Fig. 1C. Radiation coming from a heat bath at temperature $T_b$ drives transition from $b_1$ to $b_2$. Entropy sink couples $b_1$ and $b_2$ to level $\beta$ via emission of thermal photons at temperature $T_c$. Levels $a$ and $\beta$ correspond to lasing transition. For degenerate lower levels $b_1$ and $b_2$ the evolution of density matrix elements $\rho_{ab}^{\text{def}} = \rho_{\beta_1\beta_2}$ given by

$$
\dot{\rho}_{11} = \gamma_{11} [1 + n_c] \rho_{\alpha\alpha} - n_b \rho_{11} - \gamma_{11} \rho_{11} + \gamma_{11} \rho_{22} = \left[ (1 + n_c) \rho_{\alpha\alpha} - n_b \rho_{11} + \gamma_{11} \rho_{22} \right] - \left[ (1 + n_c) \rho_{\alpha\alpha} - n_b \rho_{11} + \gamma_{11} \rho_{22} \right]
$$

$$
\dot{\rho}_{22} = \gamma_{22} [1 + n_c] \rho_{\alpha\alpha} - n_b \rho_{22} - \gamma_{22} \rho_{22} + \gamma_{22} \rho_{11} = \left[ (1 + n_c) \rho_{\alpha\alpha} - n_b \rho_{22} + \gamma_{22} \rho_{11} \right] - \left[ (1 + n_c) \rho_{\alpha\alpha} - n_b \rho_{22} + \gamma_{22} \rho_{11} \right]
$$

where for maximum quantum interference $\gamma_{12b} = \sqrt{\gamma_{11} \gamma_{22}}$, $\gamma_{12c} = \sqrt{\gamma_{11} \gamma_{22}}$, while for no coherence $\gamma_{12b} = \gamma_{12c} = 0$. The laser power as determined by the net emission rate between $a$ and $\beta$ is

$$
P_{\beta} = \frac{\gamma_{12} \rho_{11} \beta (\rho_{11} + \gamma_{11} \rho_{22}) + \gamma_{22} \rho_{22} \alpha (\rho_{11} + \gamma_{11} \rho_{22}) - \gamma_{22} \rho_{22} \alpha (\rho_{11} + \gamma_{11} \rho_{22}) + \gamma_{22} \rho_{22} \alpha (\rho_{11} + \gamma_{11} \rho_{22})}{\gamma_{12} \rho_{11} \beta (\rho_{11} + \gamma_{11} \rho_{22}) + \gamma_{22} \rho_{22} \alpha (\rho_{11} + \gamma_{11} \rho_{22}) - \gamma_{22} \rho_{22} \alpha (\rho_{11} + \gamma_{11} \rho_{22}) + \gamma_{22} \rho_{22} \alpha (\rho_{11} + \gamma_{11} \rho_{22})}
$$

which yields Eq. 2 when $\tilde{\gamma}_1 \gg 1$. We focus on steady state operation. In this regime, one can easily solve Eqs. 6–10 and obtain populations and coherence $\rho_{12}$.

The photocell of Fig. 2C is very similar in spirit and mathematics to the laser QHE of Fig. 1C. However, there are a few differences. For example, the electron charge times the voltage (eV) in the photocell is replaced by $h$ in the laser. To get a simple solution for the voltage, one can simply introduce the Fermi Dirac distribution for two arbitrary levels $a$ and $\beta$

$$
\rho_{\alpha\alpha} = P_a = \frac{1}{\exp(\frac{E_{\text{F}} - E_a}{kT_1}) + 1}, \quad \rho_{\beta\beta} = P_\beta = \frac{1}{\exp(\frac{E_{\text{F}} - E_\beta}{kT_1}) + 1}.
$$

In the high temperature limit for the quantum photocell we obtain

$$
eV = \mu_a - \mu_\beta = E_a - E_\beta + kT_1 \ln \left( \frac{P_a}{P_\beta} \right).
$$

Another difference between the laser and photocell is the introduction of conduction band reservoir level $a$ as in Fig. 2B and C; and the identification of the current $j = eT_\text{res} P_\text{res}$ which does not apply for the case of the laser. To determine the laser power, we use Eq. 11. The correspondence between the laser QHE and the photocell QHE is striking and useful.

**ACKNOWLEDGMENTS.** It is a pleasure to thank our esteemed colleague George Kattawar for many enlightening discussions on optics, physics, and more. We also gratefully acknowledge support for this work by National Science Foundation Grant EEC-0540832 (MIRTHE ERC), the Office of Naval Research, and the Robert A. Welch Foundation (A-1261).


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Supporting Information

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SI Text

I. Laser QHE. Density Matrix Analysis. For the laser QHE scheme shown in Fig. S1, the density matrix equations read

\[ \dot{\rho}_{bb} = \gamma_c (1 + \tilde{n}_c) \rho_{bb} - \tilde{n}_c \rho_{ab} + \gamma_h (1 + \tilde{n}_h) \rho_{ab} - \tilde{n}_h \rho_{bb}, \]  

\[ \dot{\rho}_{bb} = \gamma_c [\tilde{n}_c \rho_{bb} - (1 + \tilde{n}_c) \rho_{bb}] + \gamma_h [(1 + \tilde{n}_h) \rho_{ab} - \tilde{n}_h \rho_{ab}], \]  

\[ \rho_{aa} + \rho_{hh} + \rho_{bb} = 1, \]  

where the laser power \( P_l \) is given by

\[ P_l = \frac{\gamma_c (1 + \tilde{n}_c)}{\gamma_h (1 + 3\tilde{n}_h) + \gamma_c (1 + 3\tilde{n}_c)} \rho \tau_c \nu_l. \]  

II. Photocell QHE: Current-Voltage Characteristics. We note that the simple analysis above can be applied to the photocell QHE of Fig. 2 by adding an extra level \( \alpha \). In this case, the solution of the density matrix equations

\[ \dot{\rho}_{bb} = \gamma_c (1 + \tilde{n}_c) \rho_{bb} - \tilde{n}_c \rho_{ab} + \gamma_h (1 + \tilde{n}_h) \rho_{ab} - \tilde{n}_h \rho_{bb}, \]  

\[ \dot{\rho}_{bb} = \gamma_c [\tilde{n}_c \rho_{bb} - (1 + \tilde{n}_c) \rho_{bb}] + \gamma_h [(1 + \tilde{n}_h) \rho_{ab} - \tilde{n}_h \rho_{ab}], \]  

\[ \rho_{aa} + \rho_{hh} + \rho_{bb} = 1, \]  

gives the current-voltage characteristics of a photocell similar to those of a pn-junction with internal resistance:

\[ j = \frac{1}{e} \frac{1 - \exp \left[ \frac{e(V - V_{oc})}{kT_c} \right]}{C + D \exp \left[ \frac{e(V + V_{oc})}{kT_c} \right]}, \]  

where the open circuit voltage \( V_{oc} \) is given by

\[ eV_{oc} = (E_a - E_b) \left( 1 - \frac{T_c}{T_h} \right). \]  

In terms of the average hot \( \tilde{n}_h \) and cold \( \tilde{n}_c \) photon (phonon) number factors, \( C \) and \( D \) read

\[ C = \gamma_c (1 + \tilde{n}_c) [3 + 2\tilde{n}_c] + \gamma_h (1 + 2\tilde{n}_h) \]  

\[ D = \gamma_c (1 + 2\tilde{n}_c) + \gamma_h (1 + 2\tilde{n}_h) \]  

The factors \( C \) has the meaning of the reverse saturation current \( j_0 \), while \( D/C \) is equivalent to \( j_0 eR/kT_c \), where \( R \) is the internal cell resistance.

III. Derivation of the Density Matrix Equations for a Three-Level Atom and Noise-Induced Coherence. Here we consider the three-level system (two lower levels, 1 and 2, and upper level \( a \) as per Fig. S3). The two lower levels, 1 and 2, have frequencies \( \omega_1 \) and \( \omega_2 \). This simple model is a building block for further analysis of the QHEs enhanced by a noise-induced coherence. In the interaction picture and the rotating-wave approximation the Hamiltonian reads

\[ \dot{\tilde{V}}(t) = h \sum_k \tilde{g}_{1k} \hat{a}_k e^{i(\omega_k - \omega_0) t} |1\rangle \langle 1| + h \sum_k \tilde{g}_{2k} \hat{a}_k e^{i(\omega_k - \omega_0) t} |2\rangle \langle 2| + \text{H.c.}, \]  

where \( \tilde{g}_{1k} \) and \( \tilde{g}_{2k} \) are the atom-photon coupling constants for transitions \( 1 \leftrightarrow 2 \) and \( 2 \leftrightarrow a \), respectively. We assume that the system interacts with a thermal reservoir described by the density operator \( \rho_R \). The equation of motion for the density operator \( \rho \) of the three-level system is given by

\[ \dot{\rho} = -\frac{i}{\hbar} \text{Tr}_R [\hat{V}(t), \rho(t_0) \otimes \rho_R (t_0)] - \frac{1}{\hbar^2} \text{Tr}_R \int_{t_0}^t [\dot{\tilde{V}}(t), \rho(t') \otimes \rho_R (t_0)] dt'. \]  

We note that \( \langle \hat{a}_k \rangle = \langle \hat{a}_k^+ \rangle = 0 \), \( \langle \hat{a}_k \hat{a}_k^+ \rangle = 0 \), \( \langle \hat{a}_k^+ \hat{a}_k^+ \rangle = \delta_{k,k} \), \( \langle \hat{a}_k \hat{a}_k^+ \rangle = \delta_{k,k+1} \), and \( \langle \hat{a}_k \hat{a}_k^+ \rangle = \langle \hat{a}_k + 1 \rangle \delta_{k,k+1} \). The sum over \( k \) may be replaced by the integral through the prescription

\[ \sum_k \int \frac{V_{ph}}{\pi} \int_0^\infty dk \frac{d^2}{dk^2}, \]  

where \( V_{ph} \) is the photon volume. In the present work, we study the steady state operation. Thus we can assume that the density matrix is a slowly varying function of time and approximate \( \dot{\rho}(t') \approx \dot{\rho}(t) \) (Markov approximation). Then the integration over time yields

\[ \int_{t_0}^t dt' e^{i(\omega_k - \omega_0) (t-t')} = \pi \delta (\omega_k - \omega_0). \]  

For nearly degenerate levels 1 and 2; i.e., if the thermal field covers both of the upper levels simultaneously, we can approximate \( \tilde{n}_k = \tilde{n}_{k_0} = n_0 \), where \( k_0 = \frac{k+1}{2} \). In the Weisskopf–Wigner approximation, we replace \( \tilde{n}_k \approx n_0 \) and obtain
\[-2\dot{\rho}(t) = \gamma_1(\{\rho(t)\} + \rho(t)) - \bar{n}_k\rho_{11}(t')\]
\[+ [\bar{n}_k\rho(t') - (\bar{n}_k + 1)\rho_{11}(t')] \{1\} \{1\}]
\[+ \gamma_{12}e^{(\omega_{12} - \nu t)}(2)[1][\bar{n}_k\rho(t) - (\bar{n}_k + 1)\rho_{11}(t')]
\[- \bar{n}_k\rho_{11}(t') \{a\} \{a\}]
\[+ \gamma_{12}e^{(\omega_{12} - \nu t)}(1)[2][\bar{n}_k\rho(t) - (\bar{n}_k + 1)\rho_{11}(t')]
\[- \bar{n}_k\rho_{22}(t') \{a\} \{a\} + \gamma_2(\{1\} [\bar{n}_k\rho(t) - (\bar{n}_k + 1)\rho_{11}(t')] + \{1\} [\bar{n}_k\rho(t) - (\bar{n}_k + 1)\rho_{11}(t')] \{a\} \{a\}]
\[+ \gamma_{12}e^{(\omega_{12} - \nu t)}(1)[2][\bar{n}_k\rho(t) - (\bar{n}_k + 1)\rho_{11}(t')]
\[- \bar{n}_k\rho_{22}(t') \{a\} \{a\}].\]

where

\[
\gamma_1 = \frac{4k_0^2V^2\rho_{11}}{\pi c}, \quad \gamma_2 = \frac{4k_0^2V^2\rho_{22}}{\pi c}, \quad \gamma_{12} = \frac{4k_0^2V^2\rho_{12}}{\pi c}.
\]

Taking the matrix elements from the operator equation and replacing \(\rho_{12} \rightarrow \rho_{12}e^{i\Delta t}\) where \(\Delta = \omega_2 - \omega_1\), we find

\[
\dot{\rho}_{11} = -\gamma_1(\bar{n}_k\rho_{11} - (\bar{n}_k + 1)\rho_{11} - \bar{n}_k\rho_{11} + 1)\rho_{11} - \frac{1}{2}\gamma_{12}^2 \dot{\bar{n}}_k \rho_{21} + \rho_{12}.\]

\[
\dot{\rho}_{22} = -\gamma_2(\bar{n}_k\rho_{22} - (\bar{n}_k + 1)\rho_{22} - \bar{n}_k\rho_{22} + 1)\rho_{22} - \frac{1}{2}\gamma_{12}^2 \dot{\bar{n}}_k \rho_{21} + \rho_{12}.\]

\[
\dot{\rho}_{12} = -\frac{1}{2}(\gamma_1 + \gamma_2)\bar{n}_k\rho_{12} + \gamma_{12}\rho_{11} - \frac{1}{2}\gamma_{12}^2 \dot{\bar{n}}_k \rho_{22} - \rho_{12} + i\Delta\rho_{12}.\]

Note that the coherence is governed by the mutual orientation of dipole moments for \(1 \rightarrow a\) and \(2 \rightarrow a\) transitions that are contained in coupling constants: \(g_{\alpha\beta} \propto \gamma\_p\). Therefore, the maximum coherence corresponds to \(\gamma_{12} = \sqrt{\gamma_1\gamma_2}\) and no coherence is present in the system when \(\gamma_{12} = 0\).

**IV. Laser QHE Enhanced by Noise-Induced Coherence.** Based on the analysis shown in Section 1 and taking into account the noise-induced coherence as per Eqs. S21–S23, the evolution of the density matrix elements for the laser QHE shown in Fig. S4 with degenerate lower levels (\(\Delta = 0\)) is described by equations

\[
\dot{\rho}_{11} = \gamma_1(\{1 + \bar{n}_c\} \rho_{11} - \bar{n}_c\rho_{11} + 1)\rho_{11} + \gamma_1(1 + \bar{n}_h)\rho_{11} - \bar{n}_h\rho_{11} - \bar{n}_h\rho_{11} + 1)\rho_{11} - \bar{n}_h\rho_{11} + 1)\rho_{11}
\[+ \gamma_{12}^2(\bar{n}_c\rho_{11} - \bar{n}_h\rho_{11} + 1)\rho_{11} - \bar{n}_h\rho_{11} + 1)\rho_{11}
\[+ \gamma_{12}^2(\bar{n}_c\rho_{11} - \bar{n}_h\rho_{11} + 1)\rho_{11} - \bar{n}_h\rho_{11} + 1)\rho_{11}
\[+ \gamma_{12}^2(\bar{n}_c\rho_{11} - \bar{n}_h\rho_{11} + 1)\rho_{11} - \bar{n}_h\rho_{11} + 1)\rho_{11}.
\]

\[
\dot{\rho}_{12} = \gamma_{12}(\{1 + \bar{n}_c\} \rho_{11} - \bar{n}_c\rho_{11} + 1)\rho_{11} + \gamma_{12}(1 + \bar{n}_h)\rho_{11} - \bar{n}_h\rho_{11} + 1)\rho_{11} - \bar{n}_h\rho_{11} + 1)\rho_{11}
\[+ \gamma_{12}^2(\bar{n}_c\rho_{11} - \bar{n}_h\rho_{11} + 1)\rho_{11} - \bar{n}_h\rho_{11} + 1)\rho_{11}.
\]

**V. Photocell QHE Enhanced by Noise-Induced Coherence. A. Noise-induced coherence: Tunneling analogy.** The laser model with two closely spaced levels (e.g., hyperfine splitting in \(^8\)Rb) is a well understood system. However, in the case of photocell it may not seem to be the case. However, we show below that there is nothing more required than simple tunneling between the adjacent quantum wells and or quantum dots.

The tunnel coupled quantum well model (see Fig. S5) yields a simple example of a doublet as per the following treatment of two quantum wells having states \(|a_1\rangle\) (RHS) and \(|a_2\rangle\) (LHS) and coupled via a tunneling interaction as shown below. The time evolution of the state vector

\[
|\Psi\rangle = |\alpha_1\rangle|\alpha_1\rangle + \alpha_2|\alpha_2\rangle
\]

is given by

\[
\dot{\alpha}_1 = -i\Delta\alpha_2,
\]

\[
\dot{\alpha}_2 = -i\Delta\alpha_1 - 2\alpha_1\alpha_2
\]

where \(\Delta\) is the coupling rate and \(\gamma\) is the rate of removing from the state \(|\alpha_2\rangle\).

In order to diagonalize the tunneling interaction, we introduce the sum and difference states
\[ \alpha_1 = \frac{1}{\sqrt{2}} (|a_2\rangle - |a_1\rangle), \]  
\[ \alpha_2 = \frac{1}{\sqrt{2}} (|a_2\rangle + |a_1\rangle). \]  
\[ |\Psi\rangle = \frac{1}{\sqrt{2}}[(a_2 - a_1)|a_1\rangle + (a_2 + a_1)|a_2\rangle]. \]  
\[ \dot{a}_2 = -(\gamma + i\Delta)a_2 - \gamma a_1, \]  
\[ \dot{a}_1 = -(\gamma - i\Delta)a_1 - \gamma a_2. \]  
\[ \rho_{11} = \gamma_c[(1 + \hat{n}_c)\rho_{\parallel\parallel} - \hat{n}_c\rho_{11}] + \gamma_b[(1 + \hat{n}_b)\rho_{bb} - \hat{n}_b\rho_{11}] \]  
\[ - (\gamma_{12}\hat{n}_c + \gamma_{12}\hat{n}_b)\text{Re}[\rho_{12}], \]  
\[ \dot{\rho}_{12} = -\frac{1}{2\tau_2}[(\gamma_{1b} + \gamma_{2b})\hat{n}_b + (\gamma_{1c} + \gamma_{2c})\hat{n}_c]\rho_{12} - \rho_{12}/\tau_2 \]  
\[ + \gamma_{12b}[(1 + \hat{n}_b)\rho_{bb} - \hat{n}_b\rho_{11} + \rho_{22}] \]  
\[ + \gamma_{12c}[(1 + \hat{n}_c)\rho_{\parallel\parallel} - \hat{n}_c\rho_{11} + \rho_{22}] \]  
\[ \dot{\rho}_{\parallel\parallel} = \gamma_c[(\hat{n}_c + 1)\rho_{\parallel\parallel} - \hat{n}_c\rho_{\parallel\parallel}] - j/e, \]  
\[ \dot{\rho}_{bb} = \gamma_c[\hat{n}_c\rho_{11} - (1 + \hat{n}_c)\rho_{\parallel\parallel}] + \gamma_b[\hat{n}_b\rho_{22} - (1 + \hat{n}_b)\rho_{\parallel\parallel}] \]  
\[ + 2\gamma_{12b}\hat{n}_b\text{Re}[\rho_{12}] + j/e. \]  
\[ \rho_{11} + \rho_{22} + \rho_{aa} + \rho_{bb} = 1, \quad j = \Gamma\rho_{aa}. \]

The current-voltage characteristics for the photocell shown in Fig. S6 is given by Eq. S11. However, factors \( C \) and \( D \) now become

\[ C = \frac{\gamma_c(1 + \hat{n}_c)(2 + 3\hat{n}_c) + \gamma_b[2 + 3\hat{n}_c + \hat{n}_b(7 + 9\hat{n}_c)]}{2\gamma_{1b}\gamma_{1c}(1 + \hat{n}_c)\hat{n}_b^2}, \]

\[ D = \frac{\gamma_c\hat{n}_c(1 + 2\hat{n}_c) + \gamma_b\hat{n}_b + 2\gamma_c(2 + 3\hat{n}_c)}{2\gamma_{1c}(1 + \hat{n}_c)\hat{n}_b^2}, \]

for the model with no coherence, and

\[ C = \frac{\gamma_c[1 + \hat{n}_c(3 + 2\hat{n}_c)] + \gamma_b[4 + 6\hat{n}_c + \hat{n}_b(7 + 9\hat{n}_c)]}{2\gamma_{1c}(1 + \hat{n}_c)^2}, \]

\[ D = \frac{\gamma_c\hat{n}_c(1 + 3\hat{n}_c + 3\hat{n}_b) + \gamma_b\hat{n}_b + 2\gamma_c(2 + 3\hat{n}_c)}{2\gamma_{1c}(1 + \hat{n}_c)\hat{n}_b^2}, \]

for the case of maximum coherence. Here coherence \( \rho_{12} \) is given by

\[ \rho_{12} = \frac{\gamma_{1c}/\gamma_{1b} - \gamma_{1b}/\gamma_{1c}}{\gamma_{1b}[1 - (\gamma_{1c}/\gamma_{1b})^2] + \gamma_b\hat{n}_b[1 - (\gamma_{1b}/\gamma_{1c})^2]} - \frac{j}{2\gamma_{1b}\hat{n}_b}, \]  
In the limit \( \hat{n}_b \ll 1, \hat{n}_c \gg 1, \gamma_c < \gamma_b \) for the system with single ground state (as per Fig. 2), the maximum current is

\[ j = \frac{1}{2}\gamma_{1b}\hat{n}_b, \]

while for the double ground state (as per Fig. 5) and no interference we have, 50% enhancement

\[ j = \frac{2}{3}\gamma_{1b}\hat{n}_b, \]

and 100% enhancement for maximum interference

\[ j = \gamma_{1b}\hat{n}_b. \]

Thus because the power of the photocell QHE is given by \( P_{\text{cell}} = j \cdot V \) and the value of voltage \( V \) that corresponds to maximum power is close to the open circuit voltage \( eV_{\text{oc}} = (E_a - E_b)(1 - T_c/T_b) \), the power delivered to the load by a photocell is essentially determined by the value of the maximum current and therefore can be doubled by invoking coherence.
Fig. S1. Scheme of laser QHE with single ground level.

Fig. S2. Scheme of photocell QHE with single ground level.

Fig. S3. Scheme of three-level system with two lower levels.

Fig. S4. Scheme of the laser QHE with double ground level.
Fig. S5. Typical intersubband double quantum well structure. Tunneling of electrons between levels $\alpha_1$ and $\alpha_2$ with coupling rate $\Delta$—(A), superposition eigenstates $a_1$ and $a_2$—(B).

Fig. S6. Scheme of photocell QHE with double ground level.